SCS230KE2

SiC Schottky Barrier Diode Datasheet

V_R	1200V
I_F	15A/30A*
Q_C	51nC

*(Per leg / Both legs)

●Outline

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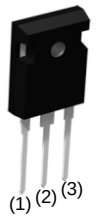


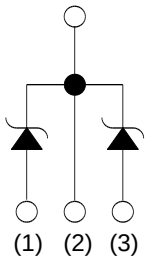
●Features

1) Shorter recovery time

2) Reduced temperature dependence

3) High-speed switching possible

●Inner circuit



(1) Anode
(2) Cathode
(3) Anode

●Construction

Silicon carbide epitaxial planer type

●Packaging specifications

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	30
	Taping code	C
	Marking	SCS230KE2

●Absolute maximum ratings (Tj = 25°C)

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	V_{RM}	1200	V
Reverse voltage (DC)	V_R	1200	V
Continuous forward current*7	I_F	15/30*1	A
Surge no repetitive forward current*7	I_{FSM}	65/130*2	A
		240/480*3	A
		49/98*4	A
Repetitive peak forward current*7	I_{FRM}	62/120*5	A
Total power disspation*7	P_D	180/360*6	W
Junction temperature	Tj	175	°C
Range of storage temperature	Tstg	−55 to +175	°C

*1 Tc=139°C/Tc=139°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C
*4 PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10%
*6 Tc=25°C *7 Per leg / Both legs

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●Electrical characteristics (Tj = 25°C) (Per leg)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	V_{DC}	I_R =0.3mA	1200	-	-	V
Forward voltage	V_F	I_F=15A,Tj=25°C	-	1.4	1.6	V
		I_F=15A,Tj=150°C	-	1.8	-	V
		I_F=15A,Tj=175°C	-	1.9	-	V
Reverse current	I_R	V_R=1200V,Tj=25°C	-	15	300	μA
		V_R=1200V,Tj=150°C	-	120	-	μA
		V_R=1200V,Tj=175°C	-	195	-	μA
Total capacitance	C	V_R=1V,f=1MHz	-	790	-	pF
		V_R=800V,f=1MHz	-	63	-	pF
Total capacitive charge	Qc	V_R=800V,di/dt=500A/μs	-	51	-	nC
Switching time	tc	V_R=800V,di/dt=500A/μs	-	18	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	Per Leg	-	0.67	0.81	°C/W
		Both Legs	-	0.34	0.41	°C/W

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●Electrical characteristic curves

Fig.1 V_F - I_F Characteristics (per leg)

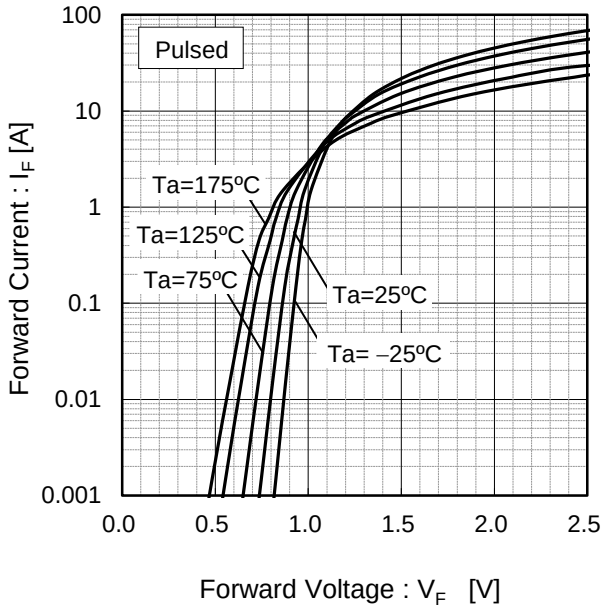


Fig.2 V_F - I_F Characteristics (per leg)

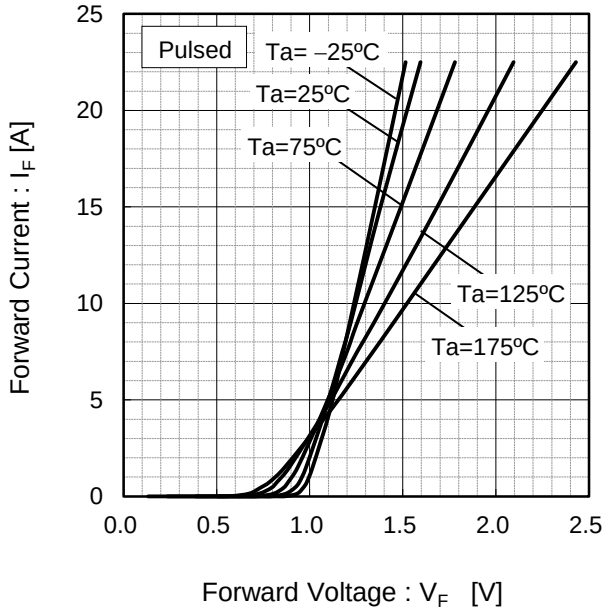


Fig.3 V_R - I_R Characteristics (per leg)

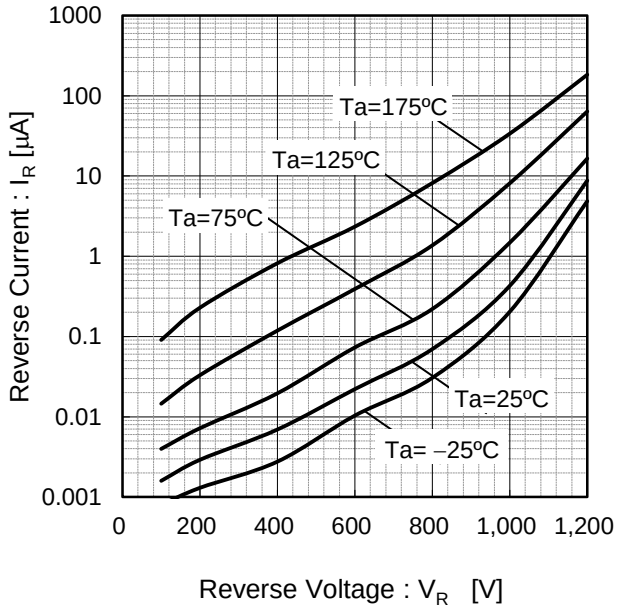
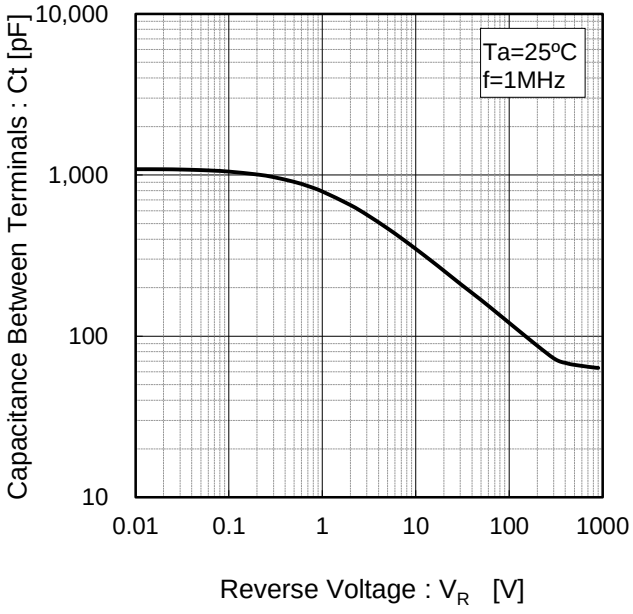


Fig.4 V_R-Ct Characteristics (per leg)



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●Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width (per leg)

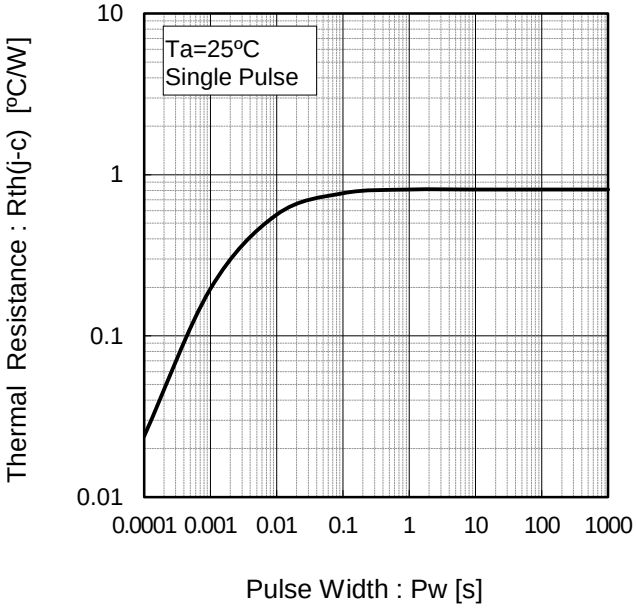


Fig.6 Power Dissipation (per leg)

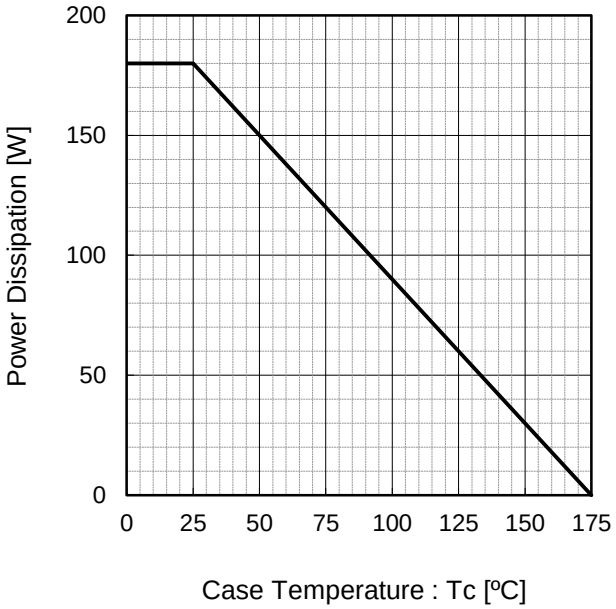


Fig.7 Ip-Tc Derating Curve (per leg)

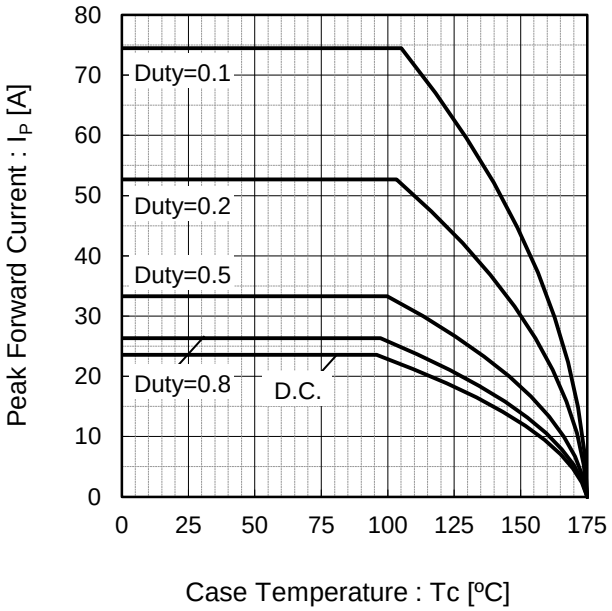
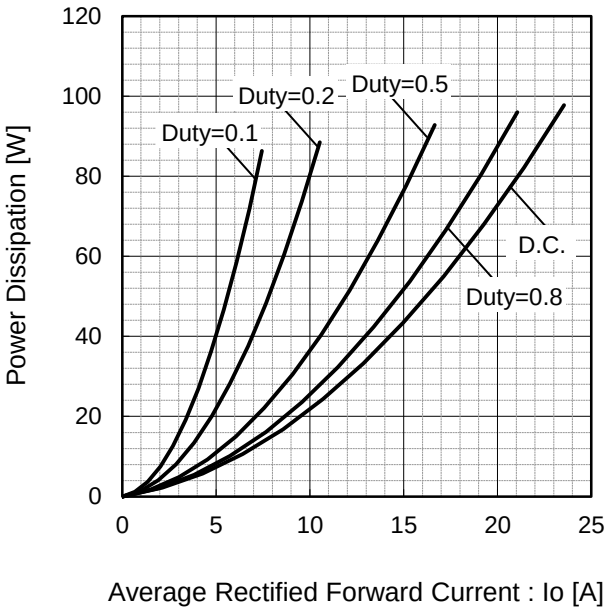


Fig.8 Io-Pf Characteristics (per leg)



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●**Dimensions** (Unit : mm)

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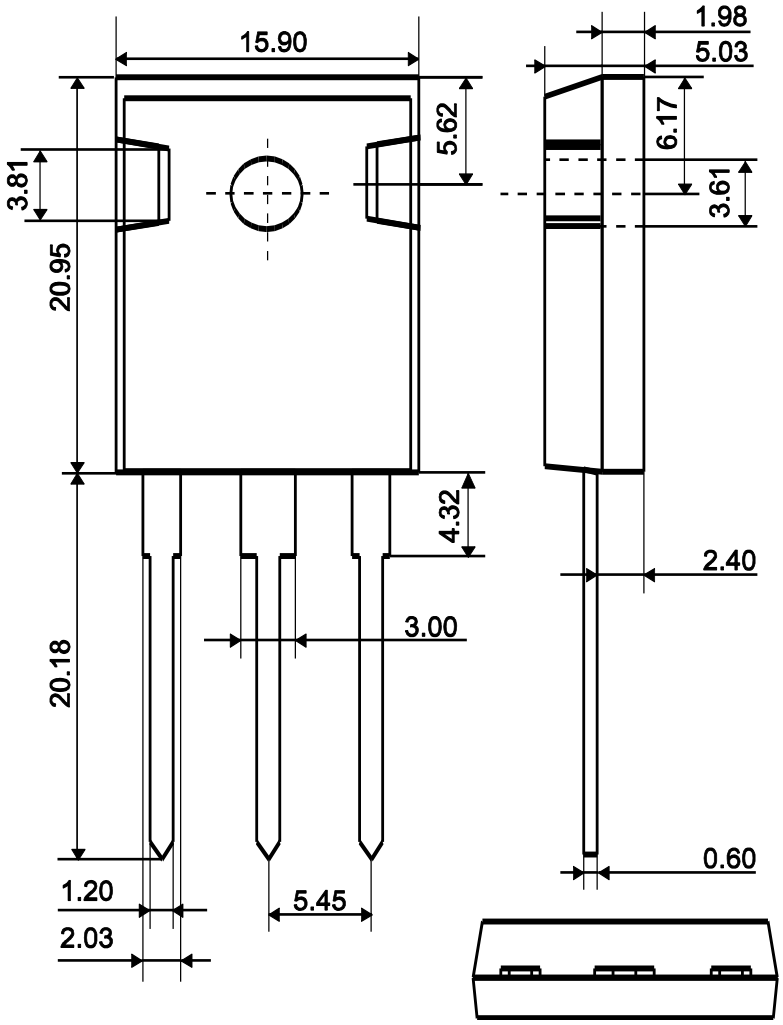

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